

# STTH102A

# HIGH EFFICIENCY ULTRAFAST DIODE

#### MAIN PRODUCT CHARACTERISTICS

I <sub>F(AV)</sub>	1A
$V_{RRM}$	200 V
Tj (max)	175 °C
V <sub>F</sub> (max)	0.78 V
trr (max)	20 ns

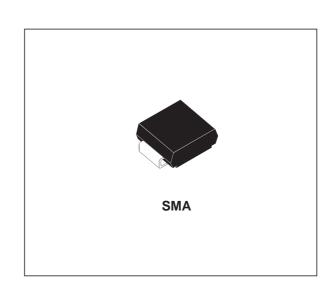
#### **FEATURES AND BENEFITS**

- Very low conduction losses
- Negligible switching losses
- Low forward and reverse recovery times
- High junction temperature



The STTH102A, which is using ST's new 200V planar technology, is specially suited for switching mode base drive & transistor circuits.

The device is also intended for use as a free wheeling diode in power supplies and other power switching applications.



### **ABSOLUTE RATINGS** (limiting values)

Symbol	Parameter	Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage	200	V
I <sub>F(AV)</sub>	Average forward current	1	Α
I <sub>FSM</sub>	Surge non repetitive forward current	40	А
T <sub>stg</sub>	Storage temperature range	+ 175	°C
Tj	Maximum operating junction temperature	175	°C

## THERMAL PARAMETERS

Symbol	Parameter	Maximum	Unit	
R <sub>th (j-l)</sub>	Junction to lead	30	°C/W	

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### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> *	Reverse leakage	Tj = 25°C	$V_R = V_{RRM}$			1	μΑ
	current	Tj = 125°C			1	25	
V <sub>F</sub> *	Forward voltage drop	Tj = 25°C	I <sub>F</sub> = 700 mA			0.90	
			I <sub>F</sub> = 1 A			0.97	
		Tj = 125°C	I <sub>F</sub> = 1 A		0.68	0.78	

Pulse test: \* tp = 5ms,  $\delta$  < 2%

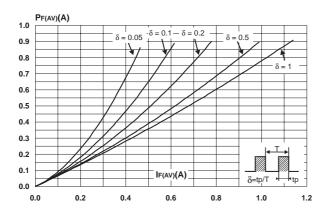
To evaluate the maximum conduction losses use the following equation : P = 0.65 x  $I_{F(AV)}$  + 0.130  $I_{F}{}^2(\text{RMS})$ 

## **DYNAMIC ELECTRICAL CHARACTERISTICS**

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
trr	Reverse recovery time	Tj = 25°C	I <sub>F</sub> = 0.5 A Irr = 0.25 A I <sub>R</sub> = 1A		12	20	ns
tfr	Forward recovery time	Tj = 25°C	$I_F = 1 \text{ A}  dI_F/dt = 50 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x V}_F\text{max}$		50		ns
V <sub>FP</sub>	Forward recovery voltage	Tj = 25°C	$I_F = 1 \text{ A}  dI_F/dt = 50 \text{ A/}\mu\text{s}$		1.8		V

<sup>\*\*</sup> tp = 380 $\mu$ s,  $\delta$  < 2%

**Fig. 1:** Average forward power dissipation versus average forward current.



**Fig. 3:** Relative variation of thermal impedance junction ambient versus pulse duration (Printed circuit board epoxy FR4).

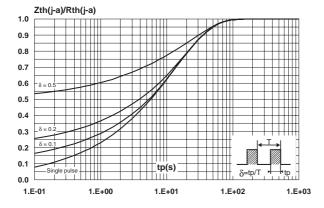


Fig. 5: Junction capacitance versus reverse voltage applied (typical values).

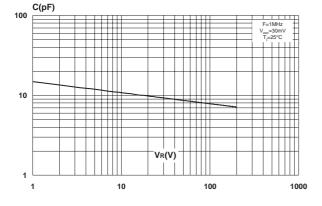
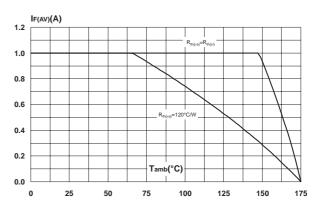
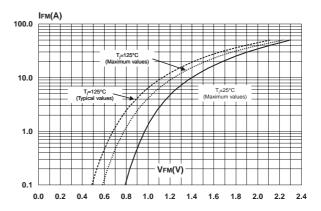


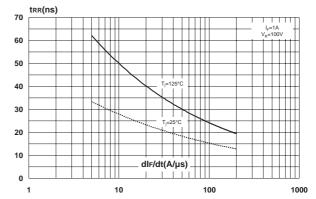
Fig. 2: Average forward current versus ambient temperature ( $\delta = 0.5$ )



**Fig. 4:** Forward voltage drop versus forward current.

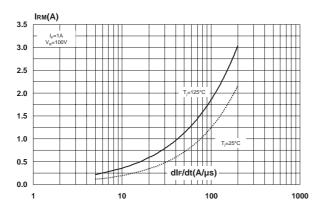


**Fig. 6:** Reverse recovery time versus dI<sub>F</sub>/dt (90% confidence).



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**Fig. 7:** Peak reverse recovery current versus dI<sub>F</sub>/dt (90% confidence).



**Fig. 9:** Relative variations of dynamic parameters versus junction temperature.

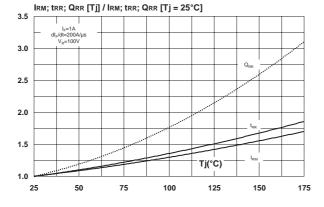


Fig. 8: Reverse recovery charges versus  $dI_F/dt$  (90% confidence).

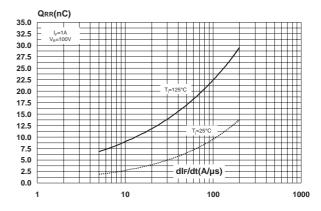
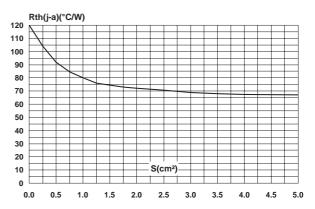


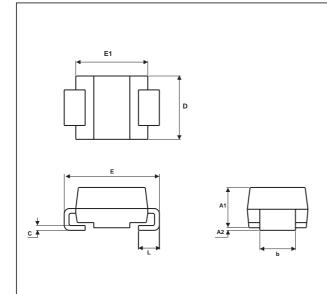
Fig. 10: Thermal resistance junction to ambient versus copper surface under each lead (epoxy FR4,  $e=35\mu m$ ).



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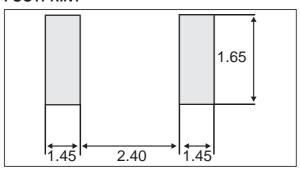
## **PACKAGE MECHANICAL DATA**

**SMA** 



	DIMENSIONS				
REF.	Millimeters		Inches		
	Min.	Min. Max.		Max.	
A1	1.90	1.90 2.70		0.106	
A2	0.05 0.20		0.002	0.008	
b	1.25	1.65	0.049	0.065	
С	0.15	0.15 0.41 4.80 5.60		0.016	
Е	4.80			0.220	
E1	3.95	4.60	0.156	0.181	
D	2.25	2.95	0.089	0.116	
L	0.75	1.60	0.030	0.063	

#### **FOOTPRINT**



Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH102A	U12	SMA	0.07 g	5000	Tape & reel

■ Epoxy meets UL 94,V0

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